

STN851-A

www.datasheet4u.com

Low voltage fast-switching NPN power transistor

Features

- AEC Q101 compliant
- Very low collector to emitter saturation voltage
- High current gain characteristic
- Fast-switching speed
- Surface-mounting SOT-223 power package in tape and reel

Applications

High efficiency low voltage switching applications



The device is manufactured in planar technology with "Base Island" layout.

The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.

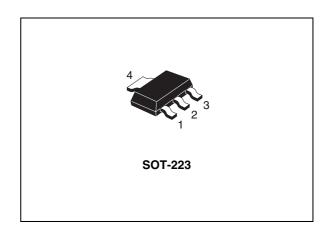


Figure 1. Internal schematic diagram

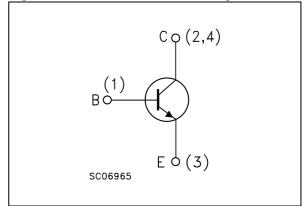


Table 1. Device summary

Order code	Marking	Package	Packaging
STN851-A	N851	SOT-223	Tape and reel

March 2009 Rev 1 1/10

Electrical ratings STN851-A

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	150	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	60	٧
V _{EBO}	Emitter-base voltage (I _C = 0)	7	V
I _C	Collector current	5	Α
I _{CM}	Collector peak current (t _P < 5 ms)	10	Α
I _B	Base current	1	Α
I _{BM}	Base peak current (t _P < 5 ms)	2	Α
P _{tot}	Total dissipation at T _{amb} = 25 °C	1.6	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-amb}	Thermal resistance junction-ambient (1)	78	°C/W

^{1.} Device mounted on a p.c.b. area of 1 cm²

2 Electrical characteristics

www.datasheet4u.com

 $(T_{case} = 25 \, ^{\circ}C \text{ unless otherwise specified})$

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = 120 V V _{CB} = 120 V	T _c = 100 °C			50 1	nΑ μΑ
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 7 V				10	nA
V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	I _C = 100 μA		150			٧
V _{(BR)CEO} ⁽¹⁾	Collector-emitter breakdown voltage (I _B = 0)	I _C = 10 mA		60			V
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C = 0)	Ι _Ε = 100 μΑ		7			V
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_{C} = 100 \text{ mA}$ $I_{C} = 1 \text{ A}$ $I_{C} = 2 \text{ A}$ $I_{C} = 5 \text{ A}$	$I_B = 50 \text{ mA}$		10 70 140 320	50 120 250 500	mV mV mV
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = 4 A	I _B = 200 mA		1	1.15	V
V _{BE(on)} (1)	Base-emitter on voltage	I _C = 4 A	V _{CE} = 1 V		0.89	1	V
h _{FE} ⁽¹⁾	DC current gain	$I_{C} = 10 \text{ mA}$ $I_{C} = 2 \text{ A}$ $I_{C} = 5 \text{ A}$ $I_{C} = 10 \text{ A}$	$V_{CE} = 1 V$ $V_{CE} = 1 V$	150 150 90 30	300 270 140 50	350	
f _T	Transition frequency	V _{CE} = 10 V	I _C = 100 mA		130		MHz
C _{CBO}	Collector-base capacitance (I _E = 0)	V _{CB} = 10 V	f = 1 MHz		50		pF
t _{on} t _s	Resistive load Turn-on time Storage time Fall time	$I_C = 1 A$ $I_{B1} = -I_{B2} = 0.$			50 1.35 120		ns µs ns

^{1.} Pulse duration = 300 μs , duty cycle $\leq 1.5\%$

577

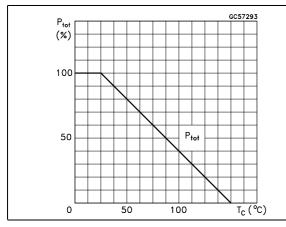
Electrical characteristics STN851-A

2.1 Electrical characteristics (curves)

Figure 2. Derating curve

Figure 3. DC current gain

www.datasheet4u.com



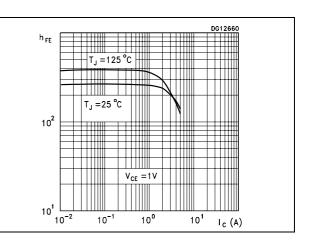
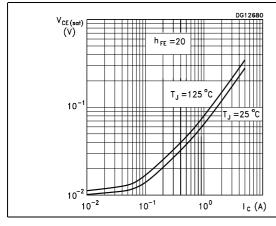


Figure 4. Collector-emitter saturation voltage

Figure 5. Collector-emitter saturation voltage



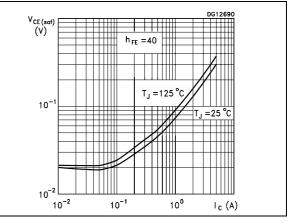
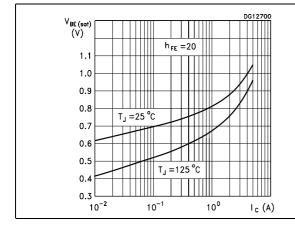
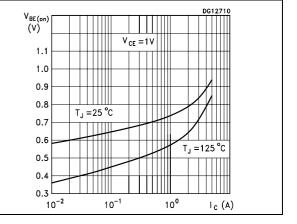


Figure 6. Base-emitter saturation voltage

Figure 7. Base-emitter on voltage

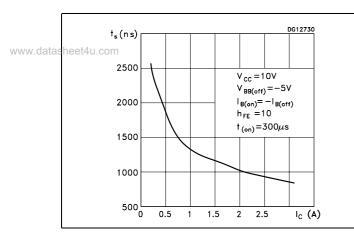




4/10

Figure 8. Resistive load switching time

Figure 9. Resistive load switching time



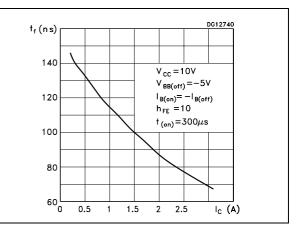
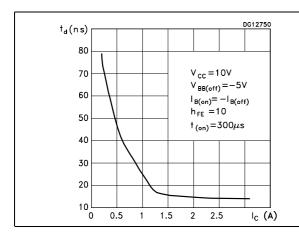


Figure 10. Resistive load switching time

Figure 11. Inductive load switching time



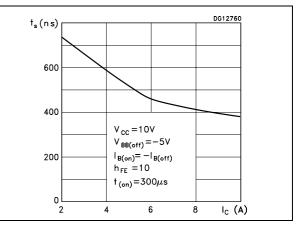
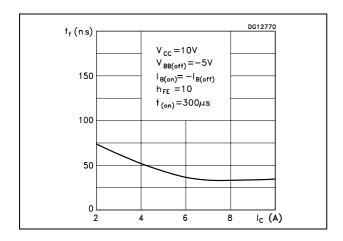


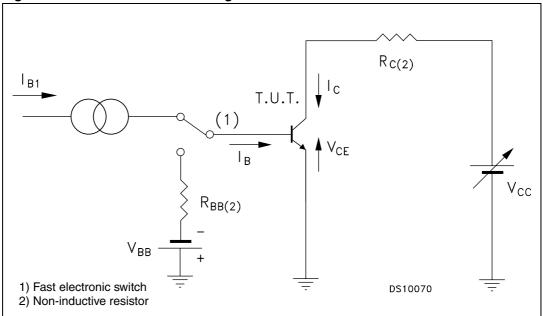
Figure 12. Inductive load switching time



577

2.2 Test circuit

Figure 13. Resistive load switching test circuit



3 Package mechanical data

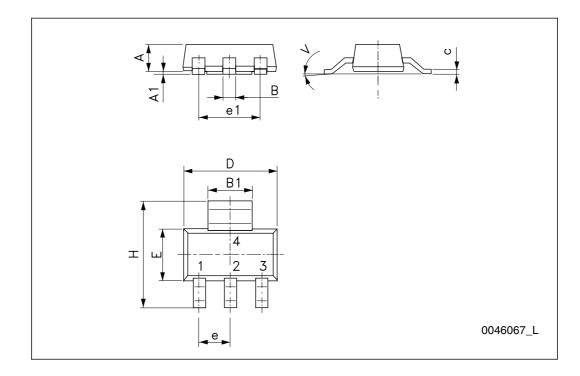
www.datasheet4u.com

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and products status are available at: www.st.com. ECOPACK is an ST trademark.

7/10

SOT-223 mechanical data

DIM.	mm.				
	min.	typ	max.		
Α			1.80		
A1	0.02		0.1		
В	0.60	0.70 0.85			
B1	2.90	2.90 3.00 3.			
С	0.24	0.26	0.35		
D	6.30	6.50	6.70		
е		2.30			
e1		4.60			
E	3.30	0 3.50 3.70			
Н	6.70	7.00 7.30			
V			10 °		



STN851-A Revision history

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
16-Mar-2009	1	First issue

www.datasheet4u.com

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZE REPRESENTATIVE OF ST, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS, WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

 $\ensuremath{\mathsf{ST}}$ and the $\ensuremath{\mathsf{ST}}$ logo are trademarks or registered trademarks of $\ensuremath{\mathsf{ST}}$ in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2009 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

